# NSN 5961-00-493-0556

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## Inclosure Material:

Metal

**Overall Length:** 

0.620 inches

## **Overall Diameter:**

0.250 inches

# **Mounting Facility Quantity:**

2

### Internal Configuration:

Junction contact

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-66

Electrode Internally-electrically Connected To Case:

Collector

### **Mounting Method:**

Unthreaded hole

## Features Provided:

Hermetically sealed case

### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage, dc and 100.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, dc

### **Current Rating Per Characteristic:**

Between 2.00 amperes source cutoff current and 4.00 amperes source cutoff current

### **Power Rating Per Characteristic:**

25.0 watts small-signal input power, common-collector absolute

### **Special Features:**

Junction pattern arrangement: pnp

### Test Data Document:

05037-1018718 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

### Terminal Type And Quantity:

1 case and 2 pin

#### Shelf Life:

N/a

### Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0